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ON Semiconductor®

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FAIRCHILD
SEMICONDUCTOR®
FDN537N
Single N-Channel Power Trench [®] MOSFET
30 V, 6.5 A, 23 m Ω

Features

- Max $r_{DS(on)} = 23 \text{ m}\Omega$ at $V_{GS} = 10 \text{ V}$, $I_D = 6.5 \text{ A}$
- Max $r_{DS(on)}$ = 36 m Ω at V_{GS} = 4.5 V, I_D = 6.0 A
- High performance trench technology for extremely low r_{DS(on)}
- High power and current handling capability in a widely used surface mount package
- Fast switching speed
- 100% UIL Tested
- RoHS Compliant

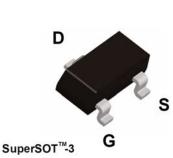


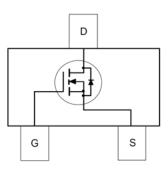
General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench[®] process that has been optimized for $r_{DS(on)}$, switching performance and ruggedness.

Application

Primary DC-DC Switch





MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DS}	Drain to Source Voltage		30	V
V _{GS}	Gate to Source Voltage	(Note 3)	±20	V
	Drain Current -Continuous (Package limited) $T_C = 25 \text{ °C}$		8.0	
I _D	-Continuous T _A = 25 °C	(Note 1a)	6.5	Α
	-Pulsed		25	
D	Power Dissipation	(Note 1a)	1.5	W
PD	Power Dissipation (Note 1b)		0.6	vv
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

P	Thermal Resistance, Junction to Ambient	(Note 1a)	80	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	180	C/ VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
537	FDN537N	SSOT-3	7 "	8 mm	3000 units

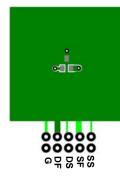
January 2013

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		18		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
I _{GSS}	Gate to Source Leakage Current, Forward	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \ \mu A$	1.2	1.8	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		-6		mV/°C
	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 6.5 A		19	23	
r _{DS(on)}		$V_{GS} = 4.5 \text{ V}, I_D = 6.0 \text{ A}$		25	36	mΩ
		V _{GS} = 10 V, I _D = 6.5 A, T _J = 125 °C		25	30	
9 _{FS}	Forward Transconductance	$V_{DD} = 5 \text{ V}, I_D = 6.5 \text{ A}$		24		S
Dynamic C _{iss}	Characteristics Input Capacitance			360	465	pF
C _{oss}	Output Capacitance	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		143	180	pF
C _{rss}	Reverse Transfer Capacitance			22	35	pF
R _g	Gate Resistance			1.0		Ω
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time			5	10	ns
t _r	Rise Time	V _{DD} = 15 V, I _D = 6.5 A,		1	10	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_{GEN} = 6 Ω		11	19	ns
t _f	Fall Time			1	10	ns
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		6.0	8.4	nC
	Total Gate Charge	$V_{GS} = 0 \text{ V to } 4.5 \text{ V}$ $V_{DD} = 15 \text{ V}$		3.0	4.2	nC
Q _{gs}	Total Gate Charge	I _D = 6.5 A		1.2		nC
Q _{gd}	Gate to Drain "Miller" Charge			1.1		nC
Drain-Sou	arce Diode Characteristics					
V _{SD}	Source to Drain Diode Forward Voltage	V _{GS} = 0 V, I _S = 6.5 A (Note 2)		0.86	1.2	V

V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 6.5 A$	(Note 2)	0.86	1.2	V
t _{rr}	Reverse Recovery Time	I _F = 6.5 A, di/dt = 100 A/μs		14	22	ns
Q _{rr}	Reverse Recovery Charge			3	10	nC

NOTES:

 $R_{0,LC}$ is guaranteed by design while R_{0CA} is determined by the user's board design.



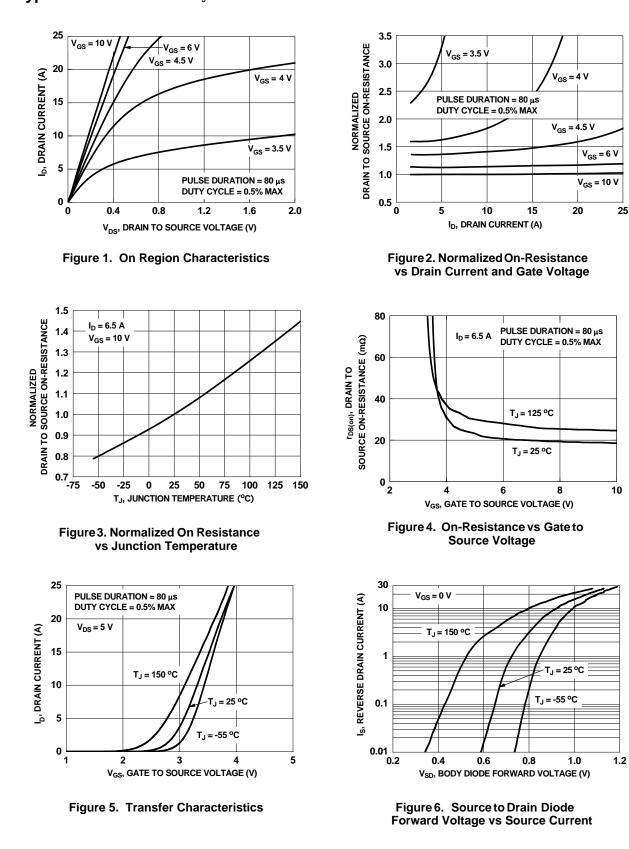


b) 180 °C/W when mounted on a minimum pad.

2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0 %.

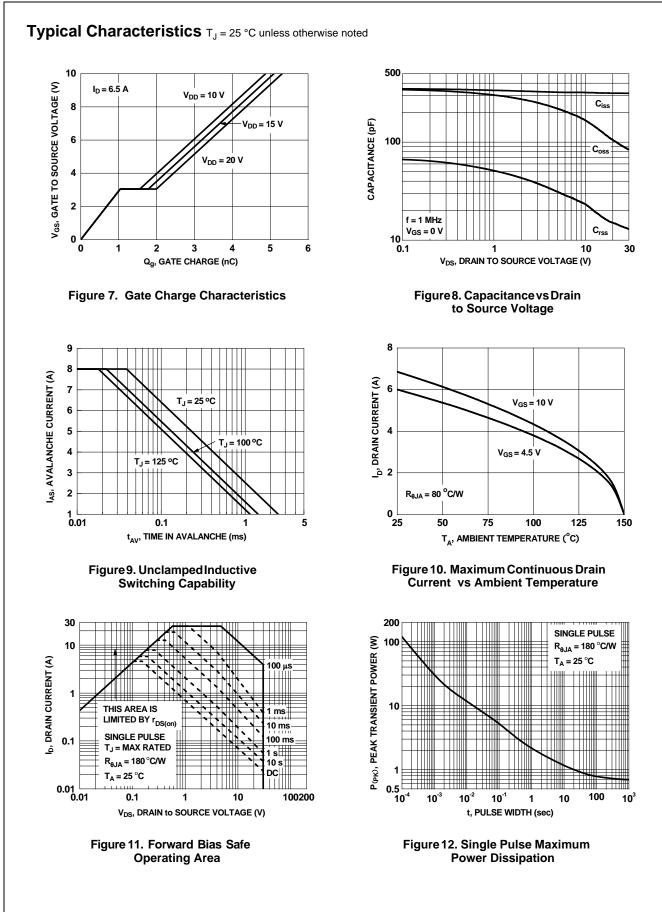
3. As an N-ch device, the negative Vgs rating is for low duty cycle pulse occurrence only. No continuous rating is implied.

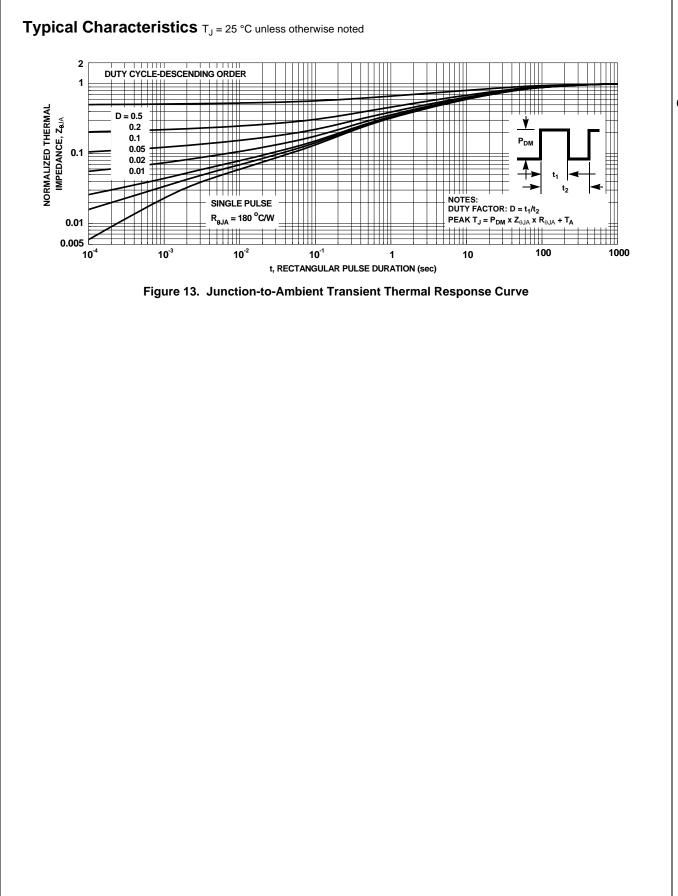
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Typical Characteristics T_J = 25 °C unless otherwise noted









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FDN537N Single N-Channel Power Trench[®] MOSFET

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